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Sheet 1 of 1

FORM PTO-1449 (Modified) INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)	Docket No. P0284US-7	Application Number 10/676,953
	Applicant TING LI et al.	
	Filing Date September 30, 2003	Group Art Unit 2826

U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
MLT	RE 34861	02/1995	DAVIS et al.	437	100	
MLT	4 946 547	08/1990	PALMOUR et al.	156	643	
MLT	5 200 022	04/1993	KONG et al.	156	612	

FOREIGN PATENT DOCUMENTS

	Document Number	Date	Country	Class	Subclass	Translation Yes	Translation No

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

MLT	1	APPLIED PHYSICS LETTERS, VOL. 79, NUMBER 15, OCT. 8, 2001, P. 2315-2317 "IMPACT OF TEXTURE-ENHANCED TRANSMISSION ON HIGH-EFFICIENCY SURFACE-TEXTURED LIGHT-EMITTING DIODES", WINDISCH et al.
	2	APPLIED PHYSICS LETTERS, VOL.63, NO. 16, OCT. 18, 1993, P. 2174-2176, "30% EXTERNAL QUANTUM EFFICIENCY FROM SURFACE TEXTURED, THIN-FILM LIGHT-EMITTING DIODES", SCHNITZER et al.
	3	IEEE JOURNAL ON SELECTED TOPICS IN QUANTUM ELECTRONICS, VOL 8, NO. 2, MARCH/APRIL 2002, P. 248-255, "LIGHT-EXTRACTION MECHANISMS IN HIGH-EFFICIENCY SURFACE-TEXTURED LIGHT-EMITTING DIODES" WINDISCH et al.
	4	IEEE JOURNAL ON SELECTED TOPICS IN QUANTUM ELECTRONICS, VOL. 8, NO. 2, MARCH/APRIL 2002, P. 321-332, "HIGH BRIGHTNESS AlGaInP LIGHT-EMITTING DIODES", STREUBEL et al.
	5	IEEE TRANSACTIONS ON ELECTRON DEVICES, VOL 47, NO. 7, JULY/2000, p. 1492-1498 "40% EFFICIENT THIN-FILM SURFACE-TEXTURED LIGHT-EMITTING DIODES BY OPTIMIZATION OF NATURAL LITHOGRAPHY", WINDISCH et al.
MLT	6	SPIE VOL 3938 (2000), LIGHT-EMITTING DIODES, MANUFACTURING, AND APPLICATIONS IV, INVITED PAPER, "NON-RESONANT CAVITY LIGHT-EMITTING DIODES", WINDISCH et al., P. 70-76

Examiner	Minh-Loan Tran	Date Considered	10/04

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through

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MLT	1	SHOR, et al."DIRECT OBSERVATION OF POROUS SIC FORMED BY ANODIZATION IN HF", APPLIED PHYSICS LETT. 62, 5/31/93, p. 2836-2838.
MLT	2	MIMURA et al., "BLUE ELECTROLUMINESCENCE FROM POROUS SILICON CARBIDE", APPLIED PHYSICS LETT. 65, 12/26/94, p. 3350-3352.
MLT	3	ZANGOOIE et al., "SURFACE, PORE MORPHOLOGY, AND OPTICAL PROPERTIES OF POROUS", JOURNAL OF THE ELECTROCHEMICAL SOCIETY, 148(6) G297-G302 (2001).

Examiner	Minh-Loan Tran	Date Considered	10/04

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.